TOSHIBA Bipolar Digital Integrated Circuit Silicon Monolithic

ULN2803APG,ULN2803AFWG,ULN2804APG,ULN2804AFWG (Manufactured by Toshiba Malaysia)

8ch Darlington Sink Driver

ULN2803APG The ULN2803APG / AFWG Series are high-voltage, ULN2804APG high-current darlington drivers comprised of eight NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads. Applications include relay, hammer, lamp and display (LED) drivers. The suffix (G) appended to the part number represents a Lead (Pb)-Free product. DIP18-P-300-2.54F ULN2803AFWG **Features** ULN2804AFWG • Output current (single output) 500 mA (Max.) High sustaining voltage output 50 V (Min.) Output clamp diodes Inputs compatible with various types of logic • : DIP-18pin Package Type–APG SOL18-P-300-1.27 • Package Type-AFWG : SOL-18pin Weight

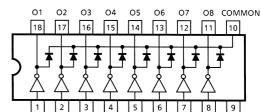
DIP18-P-300-2.54F: 1.478 g (Typ.) SOL18-P-300-1.27: 0.48 g (Typ.)

Pin Connection (top view)

12 13 14

11

Туре	Input Base Resistor	Designation	O1 O2 O3 (18 17 16
ULN2803APG / AFWG	2.7 kΩ	TTL, 5 V CMOS	
ULN2804APG / AFWG	10.5 kΩ	6~15 V PMOS, CMOS	
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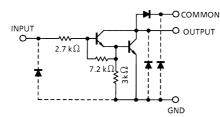
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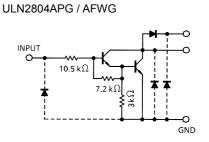
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17 18 GND

Schematics (each driver)







Note: The input and output parasitic diodes cannot be used as clamp diodes.

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Output sustaining voltage		V _{CE (SUS)}	-0.5~50	V	
Output current		I _{OUT}	500	mA / ch	.0
Input voltage		V _{IN}	-0.5~30	V	A.M.
Clamp diode reverse voltage		V _R	50	v	-0
Clamp diode forward current		١ _F	500	mΑ	C.
Power dissipation	APG	PD	1.47	W	
	AFWG	FD	0.92 / 1.31 (Note)		
Operating temperature		Topr	-40~85	°C	
Storage temperature		T _{stg}	-55~150	°C	

Note: On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%)

ULN2803,04APG/AFWG

Recommended Operating Conditions (Ta = -40~85°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit		
Output sustaining voltage		V _{CE (SUS)}		0	—	50	V		
Output current	APG	Ιουτ	T _{pw} = 25 ms, Duty = 10%, 8 Circuits	0	_	347	mA / ch		
			T _{pw} = 25 ms, Duty = 50%, 8 Circuits	0	_	123			
	AFWG		T _{pw} = 25 ms, Duty = 10%, 8 Circuits	0	_	268			
			T _{pw} = 25 ms, Duty = 50%, 8 Circuits	0	_	90			
Input voltage		V _{IN}		0	_	30	V		
Input voltage	ULN2803A	Maxim		3.5	_	30	v		
(Output on)	ULN2804A	V _{IN (ON)}		8	_	30	v		
Clamp diode reverse voltage		V _R		_	_	50	V		
Clamp diode forward current		١ _F		_	_	400	mA		
Device disation	APG	_	Ta = 85°C	—	_	0.76			
Power dissipation	AFWG	PD	Ta = 85°C (Note)	-	_	0.48	W		
Power dissipation APG $AFWG$ P_D $Ta = 85^{\circ}C$ $Ta = 85^{\circ}C$ $Ta = 85^{\circ}C$ $(Note)$ $ 0.76$ 0.48 W Note:On Glass Epoxy PCB (75 × 114 × 1.6 mm Cu 20%) V V V									

ULN2803,04APG/AFWG

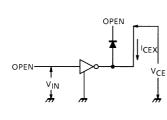
Electrical Characteristics (Ta = 25°C)

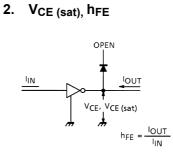
Cł	naracteristic	Symbol	Test Cir- Cuit	Test Condition		Min	Тур.	Max	Unit	
Output leakage current ULN2804A		I _{CEX}	1	V _{CE} = 50 V	Ta = 25°C		—	50	μA	
				V _{CE} = 50 V	Ta = 85°C	_	-	100		
				V _{CE} = 50 V	V _{IN} = 1 V	—	_	500		
			2	I _{OUT} = 350 mA,	I _{IN} = 500 μA	—	1.3	1.6		
Collector-emitter saturation voltage		VCE (sat)		I _{OUT} = 200 mA, I _{IN} = 350 μA		_	1.1	1.3	V	
				I _{OUT} = 100 mA,	I _{OUT} = 100 mA, I _{IN} = 250 μA		0.9	1.1		
	ULN2803A			V _{IN} = 3.85 V		_	0.93	1.35		
Input current	ULN2804A	I _{IN (ON)}	2	V _{IN} = 5 V		_	0.35	0.5	mA	
mput current	ULIN2004A			V _{IN} = 12 V		_	1.0	1.45		
		I _{IN (OFF)}	4	I _{OUT} = 500 μA, Ta = 85°C		50	65	_	μA	
	ULN2803A	Vin (on)		V _{CE} = 2 V, I _{OUT} = 200 mA		_	_	2.4		
			5	V _{CE} = 2 V, I _{OUT} = 250 mA		_	_	2.7		
				V _{CE} = 2 V, I _{OU} -	r = 300 mA 🔬	—	_	3.0	v	
Input voltage (Output on)	ULN2804A			V _{CE} = 2 V, I _{OU}	r = 125 mA	_	_	5.0		
· · · /				V _{CE} = 2 V, I _{OU}	r = 200 mA	N -	_	6.0		
				V _{CE} = 2 V, I _{OUT} = 275 mA		_	_	7.0	1	
				V _{CE} = 2 V, I _{OU}	<mark>r = 350</mark> mA	_	_	8.0	Ì	
DC current transfer ratio		h _{FE}	2	V _{CE} = 2 V, I _{OUT} = 350 mA		1000	_	_		
Clamp diode reverse current		IR	6	Ta = 25°C	(Note)	_	_	50		
				Ta = 85°C	(Note)	_	_	100	μA	
Clamp diode forward voltage		VF	7	I _F = 350 mA		_	_	2.0	V	
Input capacitance		CIN	_				15	I	pF	
Turn-on delay		ton	8	R _L = 125 Ω, V _O	UT = 50 V		0.1	_	— µs	
Turn-off delay		tOFF	ō	R _L = 125 Ω, V _O	UT = 50 V	—	0.2	_		

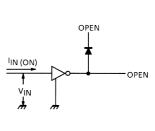
Note: $V_R = V_R MAX$.

Test Circuit

1. I_{CEX}





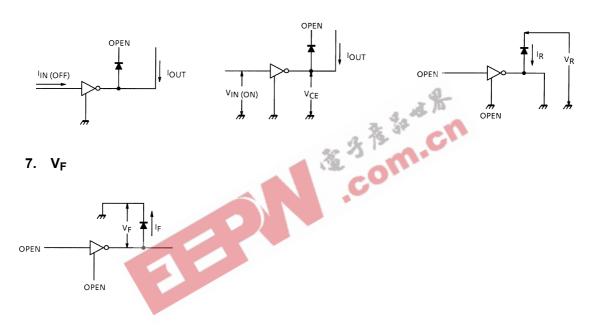


4. IIN (OFF)

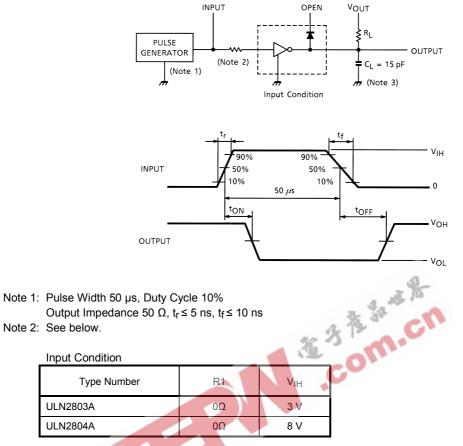
5. V_{IN (ON)}

6. I_R

3. I_{IN (ON)}



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Note 3: CL includes probe and jig capacitance

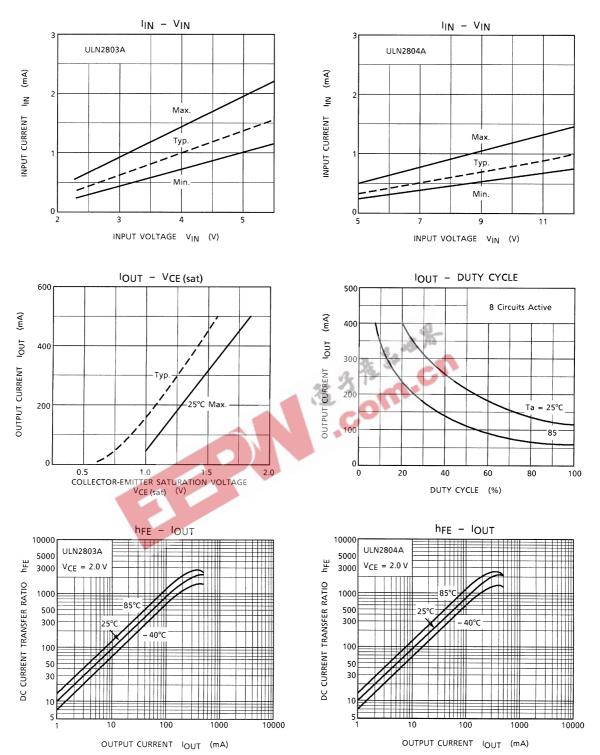
Precautions for Using

This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

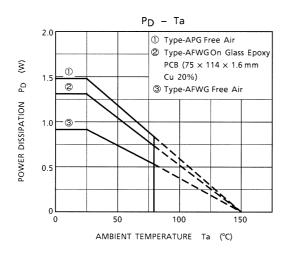
Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

ULN2803,04APG/AFWG



ULN2803,04APG/AFWG

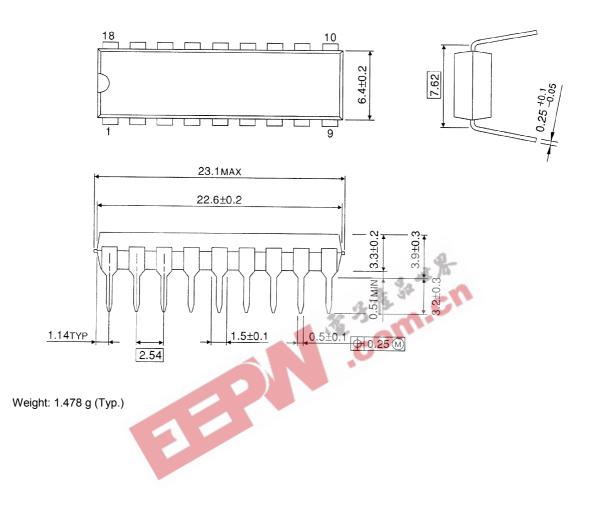




Package Dimensions

DIP18-P-300-2.54F

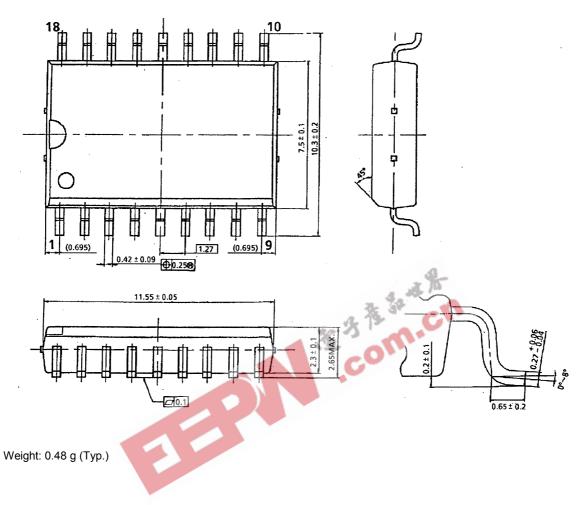
Unit: mm



Package Dimensions

SOL18-P-300-1.27

Unit: mm



Notes on Contents

1. Schematics

The schematics may be simplified or some parts of them may be omitted for explanatory purposes.

2. Absolute Maximum Ratings

The absolute maximum ratings of a semiconductor device are a set of specified parameter values that must not be exceeded during operation, even for an instant.

If any of these ratings are exceeded during operation, the electrical characteristics of the device may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed.

Moreover, any exceeding of the ratings during operation may cause breakdown, damage and/or degradation in other equipment. Applications using the device should be designed so that no absolute maximum rating will ever be exceeded under any operating conditions.

Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

3. Recommended Operating Conditions

The values of the conditions are applied within the range of the operating temperature and not guaranteed.

4. AC Characteristics

AC characteristics that mean turn-on and turn-off time are targeted design values and not guaranteed.

5. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially in the phase of mass production design. In furnishing these examples of application circuits, Toshiba does not grant the use of any industrial property rights.

6. Graphics Characteristics

Graphics characteristics are reference ones and not guaranteed.

Handling of the IC

Ensure that the product is installed correctly to prevent breakdown, damage and/or degradation in the product or equipment.

About solderability, following conditions were confirmed

- Solderability
 - (1) Use of Sn-37Pb solder Bath
 - · solder bath temperature = $230^{\circ}C$
 - · dipping time = 5 seconds
 - \cdot the number of times = once
 - use of R-type flux
 - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - solder bath temperature = 245°C
 - · dipping time = 5 seconds
 - \cdot the number of times = once
 - use of R-type flux

RESTRICTIONS ON PRODUCT USE

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- The information contained herein is subject to change without notice. 021023_D
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor
 devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
 stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety
 in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such
 TOSHIBA products could cause loss of human life, bodily injury or damage to property.

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In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc. 021023_A

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